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Silicon Carbide Schottky Diode 1200 V, 50 A

NDSH50120C

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 380 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Halogen Free/BFR Free and are RoHS Compliant

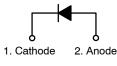
Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

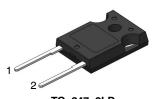


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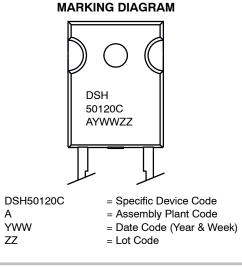
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Schottky Diode



TO-247-2LD CASE 340DA



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage		1200	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)		380	mJ
١ _F	Continuous Rectified Forward Current @ T _C < 139°C		50	А
	Continuous Rectified Forward Current @ $T_C < T_C$	53		
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	1568	А
		T _C = 150°C, 10 μs	1414	А
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	231	А
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	84	А
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	375	W
		T _C = 150°C	62.5	W
T _J , T _{STG}	Operating and Storage Temperature Range		–55 to +175	°C

ABSOLUTE MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. E_{AS} of 380 mJ is based on starting $T_J = 25^{\circ}$ C, L = 0.5 mH, $I_{AS} = 39$ A, V = 50 V.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	0.4	°C/W
$R_{ hetaJA}$	R _{0JA} Thermal Resistance, Junction to Ambient, Max		°C/W

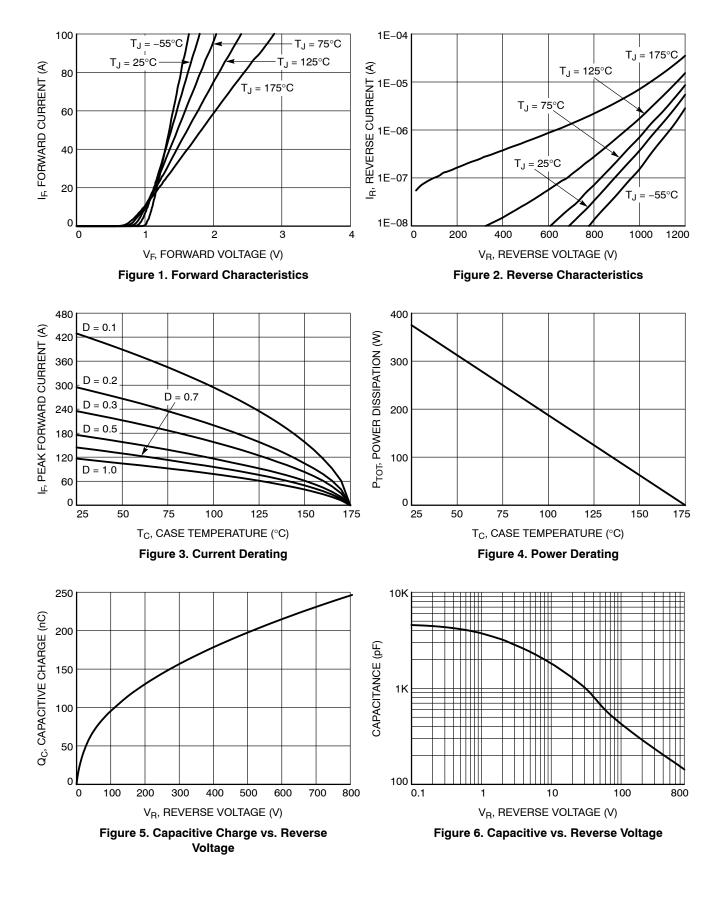
ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F	Forward Voltage	I _F = 50 A, T _J = 25°C	-	1.4	1.75	V
		I _F = 50 A, T _J = 125°C	-	1.63	-	
		I _F = 50 A, T _J = 175°C	-	1.84	-	
I _R	Reverse Current	$V_{R} = 1200 \text{ V}, \text{ T}_{J} = 25^{\circ}\text{C}$	-	12.2	200	μΑ
		V_{R} = 1200 V, T_{J} = 125°C	-	30	200	
		V_{R} = 1200 V, T_{J} = 175°C	-	61.5	200	
Q _C	Total Capacitive Charge	V = 800 V	-	246	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	3691	-	pF
		V _R = 400 V, f = 100 kHz	-	198	-	
		V _R = 800 V, f = 100 kHz	-	143	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
NDSH50120C	DSH50120C	TO-247-2LD (Pb-Free / Halogen Free)	30 Units / Tube



TYPICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)



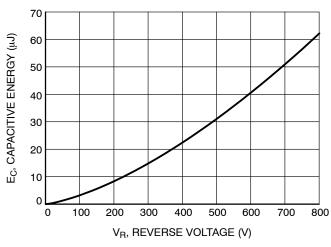


Figure 7. Capacitance Stored Energy

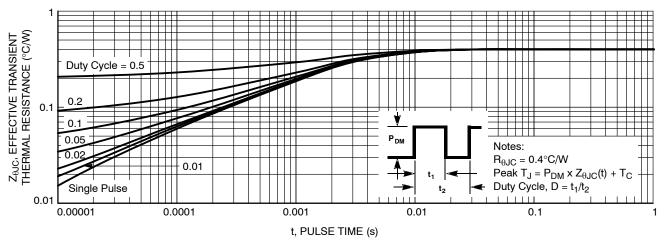
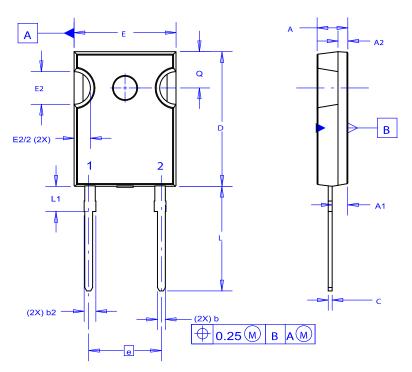


Figure 8. Junction-to-Case Transient Thermal Response Curve

PACKAGE DIMENSIONS

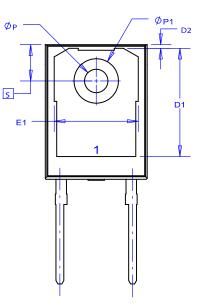




NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.B. ALL DIMENSIONS ARE IN MILLIMETERS.

- C. DRAWING CONFORMS TO ASME Y14.5 2009. D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.



	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	4.58	4.70	4.82		
A1	2.20	2.40	2.60		
A2	1.40	1.50	1.60		
b	1.17	1.26	1.35		
b2	1.53	1.65	1.77		
с	0.51	0.61	0.71		
D	20.32	20.57	20.82		
D1	13.08	~	~		
D2	0.51	0.93	1.35		
E	15.37	15.62	15.87		
E1	12.81	~	~		
E2	4.96	5.08	5.20		
е	~	11.12	~		
L	15.75	16.00	16.25		
L1	3.69	3.81	3.93		
ØР	3.51	3.58	3.65		
Ø P1	6.60	6.80	7.00		
Q	5.34	5.46	5.58		
S	5.34	5.46	5.58		

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